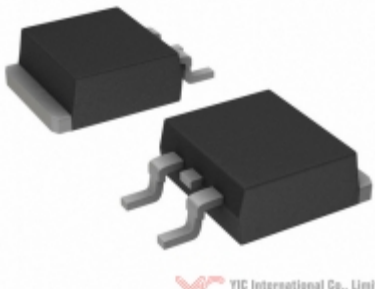

	<h2 style="color: red;">FQB4P25TM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB4P25TM
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET P-CH 250V 4A D2PAK
	Datenblätter:  FQB4P25TM.pdf
	RoHS Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 1600 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB4P25TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET P-CH 250V 4A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	1600 pcs Stock
detaillierte Beschreibung	P-Channel 250V 4A (Tc) 3.13W (Ta), 75W (Tc) Surface
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 75W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	250V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4A (Tc)
Rds On (Max) @ Id, Vgs	2.1 Ohm @ 2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	14nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	420pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)


















FQB4P25TM ist neu im Original, Suche FQB4P25TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB4P25TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB4P25TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB4N90 FSC FQB4N90 FSC</p>	 <p>FQB4P40TM Fairchild/ON Semiconductor MOSFET P-CH 400V 3.5A D2PAK</p>	 <p>FQB4P25TM Fairchild/ON Semiconductor MOSFET P-CH 250V 4A D2PAK</p>	 <p>FQB4N90TM Fairchild/ON Semiconductor MOSFET N-CH 900V 4.2A D2PAK</p>
 <p>FQB4N90TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 900V 4.2A D2PAK</p>	 <p>FQB50N03 VB FQB50N03 VB</p>	 <p>FQB5050CFTM Fairchild Fairchild TO-263</p>	 <p>FQB4P40 FAIRCHIL FQB4P40 FAIRCHIL</p>

heiße Teile

Mehr

 FQB3P50TM	 FQB3P50TM	 FQB44N10	 FQB44N10TM	 FQB44N10TM
 FQB46N15	 FQB46N15TM	 FQB47P06	 FQB47P06TM	 FQB4N20L
 FQB4N20LTM	 FQB4N20LTM	 FQB4N20TM	 FQB4N20TM	 FQB4N25TM
 FQB4N25TM	 FQB4N20TM	 FQB4N50TM	 FQB4N50TM	 FQB4N60C
 FQB4N80TM	 FQB4N80TM	 FQB4N90TM	 FQB4N90TM	 FQB4P25TM
 FQB50N03	 FQB50N06	 FQB50N06C	 FQB50N06L	 FQB50N06LTM
 FQB50N06LTM	 FQB50N06M	 FQB50N06TM	 FQB50N06TM	 FQB50N06TM-NL
 FQB55N06TM	 FQB55N06TM	 FQB55N10	 FQB55N10TM	 FQB55N10TM
 FQB5N20L	 FQB5N30TM	 FQB5N30TM	 FQB5N50C	 FQB5N50CF
 FQB5N50CTM	 FQB5N50CTM	 FQB5N60CTM	 FQB5N60CTM	 FQB5N90TM

Contact us: Info@Y-IC.com

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